

ESDA6V1BC6

ASD™

QUAD BIDIRECTIONAL TRANSIL™ SUPPRESSOR FOR ESD PROTECTION

MAIN APPLICATIONS

Where transient overvoltage protection in ESD sensitive equipment is required, such as:

- Computers
- Printers
- Communication systems
- Video equipment

This device is particularly adapted to the protection of symmetrical signals

FEATURES

- 4 Bidirectional Transil functions
- ESD Protection for data, Signal and V_{CC} Bus
- Stand off voltage range: ± 5 V
- Low leakage current < 1µA</p>
- Peak pulse power (8/20µs); 80W

DESCRIPTION

The ESDA6V1BC6 is a monolithic array designed to protect up to 4 lines in a bidirectional way against ESD transients.

The device is ideal for situations where board space is at a premium.

BENEFITS

- High ESD protection level: up to 25kV
- High integration
- Suitable for high density boards

COMPLIES WITH THE FOLLOWING STANDARDS:

■ IEC61000-4-2 level 4:

15kV (air discharge)8kV (contact discharge)

■ MIL STD 883E-Method 3015-6: class3 (Human Body Model)

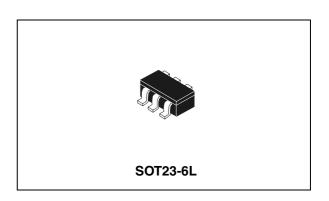
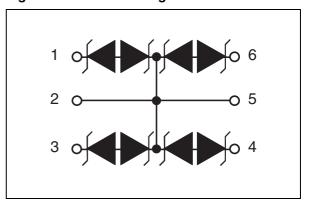


Table 1: Order Code

Part Number	Marking		
ESDA6V1BC6	BS55		

Figure 1: Functional Diagram



TM: ASD is a trademark of STMicroelectronics.

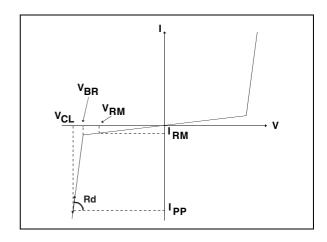
Table 2: Absolute Maximum Ratings $(T_{amb} = 25^{\circ}C)$

Symbol	P	Value	Unit	
V _{PP}	ESD discharge	MIL STD 883C - Method 3015-6 IEC61000-4-2 air discharge IEC61000-4-2 contact discharge	25 15 8	kV
P _{PP}	Peak pulse power (8/20µs)	80	W	
Tj	Junction temperature	150	°C	
T _{stg}	Storage temperature range	-55 to +150	°C	
TL	Maximum lead temperature fo case	260	°C	
T _{op}	Operating temperature range	-40 to +125	°C	

Note 1: Variation of parameters is given by curves.

Table 3: Electrical Characteristics $(T_{amb} = 25^{\circ}C)$

Symbol	Parameter
V _{RM}	Stand-off voltage
V_{BR}	Breakdown voltage
V _{CL}	Clamping voltage
I _{RM}	Leakage current
I _{PP}	Peak pulse current
αΤ	Voltage temperature coefficient
V _F	Forward voltage drop
С	Capacitance
R _d	Dynamic resistance



	\	/ _{BR} @	I _R	I _{RM} @	V _{RM}	R_d	α T	С
Type	min.	max.		max.		typ.	max.	typ.
Туре						note 2		0V bias
	V	V	mA	μΑ	V	Ω	10 ⁻⁴ /°C	pF
ESDA6V1BC6	6.1	8	1	1	5	1.35	3	20

Note 2: Square pulse, Ipp = 3A, t_p =2.5 μ s.

Figure 2: Relative variation of peak pulse power versus initial junction temperature

Ppp[Tj initial] / Ppp[Tj initial=25°C]

1.1
1.0
0.9
0.8
0.7
0.6
0.5
0.4
0.3
0.2
0.1
0.0
0 25 50 75 100 125 150 173

Figure 3: Peak pulse power versus exponential pulse duration

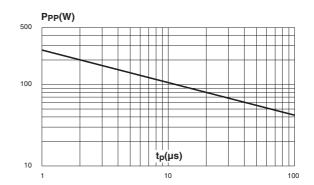


Figure 4: Clamping voltage versus peak pulse current (typical values, rectangular waveform)

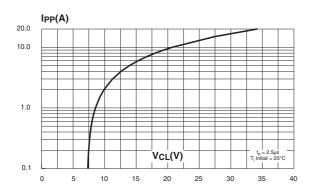


Figure 5: Junction capacitance versus line voltage applied (typical values

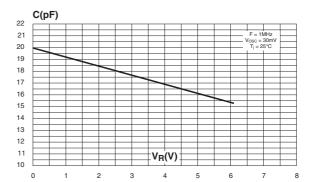
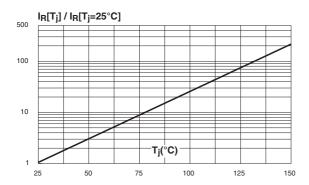


Figure 6: Relative variation of leakage current versus junction temperature (typical values)



1. ESD protection by ESDA6V1-4BC6

With the focus of lowering the operation levels, the problem of malfunction caused by the environment is critical. Electrostatic discharge (ESD) is a major cause of failure in electronic system.

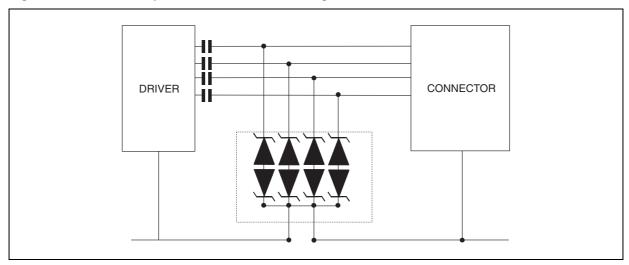
Transient Voltage Suppressors are an ideal choice for ESD protection and have proven capable in suppressing ESD events. They are capable of clamping the incoming transient to a low enough level such that damage to the protected semiconductor is prevented.

Surface mount TVS arrays offer the best choice for minimal lead inductance.

They serve as parallel protection elements, connected between the signal line to ground. As the transient rises above the operating voltage of the device, the TVS array becomes a low impedance path diverting the transient current to ground.

5//.

Figure 7: Bidirectional protection for 0V biased signals



The ESDA6V1BC6 array is the ideal product for use as board level protection of ESD sensitive semiconductor components.

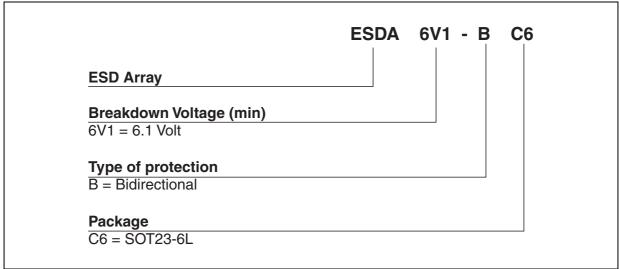
The tiny SOT23-6L package allows design flexibility in the design of "crowded" boards where the space saving is at a premium. This enables to shorten the routing and can contribute to improve ESD performance.

2. Circuit Board Layout

Circuit board layout is a critical design step in the suppression of ESD induced transients. The following guidelines are recommended:

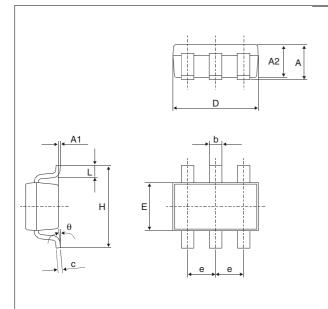
- The ESDA6V1BC6 should be placed as near as possible to the input terminals or connectors.
- Minimise the path length between the ESD suppressor and the protected device
- Minimise all conductive loops, including power and ground loops
- The ESD transient return path to ground should be kept as short as possible.
- Use ground planes whenever possible.

Figure 8: Ordering information scheme



577

Figure 9: SOT23-6L Package Mechanical Data



	DIMENSIONS					
REF.	Mi	llimete	rs	rs Inche		
	Min.	Тур.	Max.	Min.	Тур.	Max.
Α	0.90		1.45	0.035		0.057
A1	0		0.10	0		0.004
A2	0.90		1.30	0.035		0.051
b	0.35		0.50	0.014		0.02
С	0.09		0.20	0.004		0.008
D	2.80		3.05	0.110		0.120
Е	1.50		1.75	0.059		0.069
е		0.95			0.037	
Н	2.60		3.00	0.102		0.118
L	0.10		0.60	0.004		0.024
θ			10°			10°

Figure 10: Foot Print Dimensions (in millimeters)

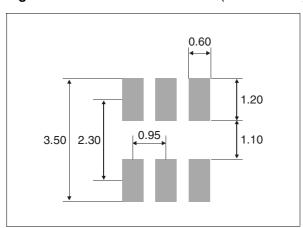


Table 4: Ordering Information

Part Number	Marking	Package	Weight	Base qty	Delivery mode
ESDA6V1BC6	BS55	SOT23-6L	16.7 mg	3000	Tape & reel

Table 5: Revision History

Date	Revision	Description of Changes
Jan-2002	1A	First issue.
4-Nov-2004	2	SOT23-6L package dimensions change for reference "D" from 3.0 millimeters (0.118 inches) to 3.05 millimeters (0.120 inches).

ESDA6V1BC6

Information furnished is believed to be accurate and reliable. However, STMicroelectronics assumes no responsibility for the consequences of use of such information nor for any infringement of patents or other rights of third parties which may result from its use. No license is granted by implication or otherwise under any patent or patent rights of STMicroelectronics. Specifications mentioned in this publication are subject to change without notice. This publication supersedes and replaces all information previously supplied. STMicroelectronics products are not authorized for use as critical components in life support devices or systems without express written approval of STMicroelectronics.

The ST logo is a registered trademark of STMicroelectronics. All other names are the property of their respective owners

© 2004 STMicroelectronics - All rights reserved

STMicroelectronics group of companies

Australia - Belgium - Brazil - Canada - China - Czech Republic - Finland - France - Germany - Hong Kong - India - Israel - Italy - Japan - Malaysia - Malta - Morocco - Singapore - Spain - Sweden - Switzerland - United Kingdom - United States of America www.st.com



X-ON Electronics

Largest Supplier of Electrical and Electronic Components

Click to view similar products for ESD Suppressors / TVS Diodes category:

Click to view products by STMicroelectronics manufacturer:

Other Similar products are found below:

60KS200C D12V0H1U2WS-7 D18V0L1B2LP-7B 82356050220 D5V0M5U6V-7 NTE4902 P4KE27CA P6KE11CA P6KE39CA-TP
P6KE8.2A SA110CA SA60CA SA64CA SMBJ12CATR SMBJ8.0A SMLJ30CA-TP ESD101-B1-02ELS E6327 ESD112-B1-02EL E6327
ESD119B1W01005E6327XTSA1 ESD5V0L1B02VH6327XTSA1 ESD7451N2T5G 19180-510 CPDT-5V0USP-HF 3.0SMCJ33CA-F
3.0SMCJ36A-F HSPC16701B02TP D3V3Q1B2DLP3-7 D55V0M1B2WS-7 DESD5V0U1BL-7B DRTR5V0U4SL-7 SCM1293A-04SO
ESD200-B1-CSP0201 E6327 ESD203-B1-02EL E6327 SM12-7 SMF8.0A-TP SMLJ45CA-TP CEN955 W/DATA 82350120560
82356240030 VESD12A1A-HD1-GS08 CPDUR5V0R-HF CPDUR24V-HF CPDQC5V0U-HF CPDQC5V0USP-HF CPDQC5V0-HF
D1213A-01LP4-7B D1213A-02WL-7 ESDLIN1524BJ-HQ 5KP100A 5KP15A